

BD901-S

BD901-S Information

Heisener.com	Part Number	BD901-S
	Manufacturer	Bourns Inc.
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
	Description	TRANS NPN DARL 100V 8A
	Package	TO-220-3
		For the pricing/inventory/lead time, please contact
For Reference Only		us
		Website: https://www.heisener.com
		E-mail: salesdept@heisener.com



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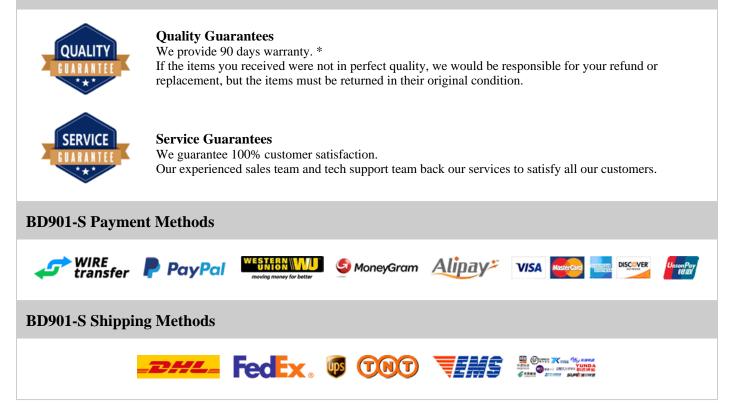


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BD901-S Specifications

Manufacturer Part NumberBD901-SManufacturerBourns Inc.CategoryDiscrete Semiconductor Products Transistors - Bipolar (BJT) - SinglePackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Le) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADCurrent Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3		DD001.0
CategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - SinglePackageTo-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVec Saturation (Max) @ Ib, IcSo0µACurrent - Collector Cutoff (Max)500µAPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTo-220-3Supplier Device PackageTo-220-3	Manufacturer Part Number	BD901-S
Transistors - Bipolar (BJT) - SinglePackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Manufacturer	Bourns Inc.
PackageTO-220-3Series-Transistor TypeNPN - DarlingtonCurrent - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Category	Discrete Semiconductor Products
Series-Series-Transistor TypeNPN - DarlingtonCurrent - Collector (L) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - MaxQWFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3		Transistors - Bipolar (BJT) - Single
Transistor TypeNPN - DarlingtonCurrent - Collector (LMAX)8AVoltage - Collector Emitter Breakdown (Max)100VVcc Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Package	TO-220-3
Current - Collector (Ic) (Max)8AVoltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Series	-
Voltage - Collector Emitter Breakdown (Max)100VVce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Transistor Type	NPN - Darlington
Vce Saturation (Max) @ Ib, Ic2.5V @ 12mA, 3ACurrent - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Current - Collector (Ic) (Max)	8A
Current - Collector Cutoff (Max)500µADC Current Gain (hFE) (Min) @ Ic, Vce750 @ 3A, 3VPower - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Voltage - Collector Emitter Breakdown (Max)	100V
DC Current Gain (hFE) (Min) @ Ic, Vce 750 @ 3A, 3V Power - Max 2W Frequency - Transition - Operating Temperature -65°C ~ 150°C (TJ) Mounting Type Through Hole Package / Case TO-220-3 Supplier Device Package TO-220-3	Vce Saturation (Max) @ Ib, Ic	2.5V @ 12mA, 3A
Power - Max2WFrequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Current - Collector Cutoff (Max)	500μΑ
Frequency - Transition-Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	DC Current Gain (hFE) (Min) @ Ic, Vce	750 @ 3A, 3V
Operating Temperature-65°C ~ 150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Power - Max	2W
Mounting TypeThrough HolePackage / CaseTO-220-3Supplier Device PackageTO-220-3	Frequency - Transition	-
Package / CaseTO-220-3Supplier Device PackageTO-220-3	Operating Temperature	-65°C ~ 150°C (TJ)
Supplier Device Package TO-220-3	Mounting Type	Through Hole
	Package / Case	TO-220-3
Report errors?	Supplier Device Package	TO-220-3
		Report errors?

BD901-S Guarantees



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